



**DMP2900UT** 

### P-CHANNEL ENHANCEMENT MODE MOSFET

### **Product Summary**

BV <sub>DSS</sub>	Rds(on)	I <sub>D</sub> T <sub>A</sub> = +25°C
	700mΩ @ V <sub>GS</sub> = -4.5V	-0.5A
-20V	900mΩ @ V <sub>GS</sub> = -2.5V	-0.48A
	1300mΩ @ V <sub>GS</sub> = -1.8V	-0.4A

## **Description and Applications**

This new generation MOSFET is designed to minimize the on-state resistance ( $R_{DS(ON)}$ ) and yet maintain superior switching performance, making it ideal for high efficiency power management applications.

- DC-DC Converters
- Load Switch
- Power Management Functions





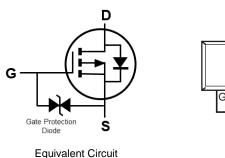
**SOT523** 

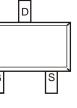
Top View

- **Features and Benefits**
- Low On-Resistance
- Low Gate Threshold Voltage
- Low Input Capacitance
- Fast Switching Speed
  Low Input/Output Leakage
- ESD Protected Gate
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- For automotive applications requiring specific change control (i.e. parts qualified to AEC-Q100/101/200, PPAP capable, and manufactured in IATF 16949 certified facilities), please <u>contact us</u> or your local Diodes representative. <u>https://www.diodes.com/guality/product-definitions/</u>

### **Mechanical Data**

- Case: SOT523
- Case Material: Molded Plastic, "Green" Molding Compound.
   UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Matte Tin Annealed over Alloy 42 Leadframe. Solderable per MIL-STD-202, Method 208 ©3
- Terminal Connections: See Diagram
- Weight: 0.002 grams (Approximate)





Top View

## Ordering Information (Note 4)

	Part Number	Case	Packaging			
	DMP2900UT-7	SOT523	3000/Tape & Reel			
	DMP2900UT-13	SOT523	10000/Tape & Reel			
Notes:	s: 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant.					

No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant.
 See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.

3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.</p>

4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.

## **Marking Information**

	RA1	ΥM
Т		

RA1 = Product Type Marking Code YM = Date Code Marking Y or  $\overline{Y}$  = Year (ex: H = 2020) M = Month (ex: 9 = September)

#### Date Code Key

Date Code Key												
Year	2019	2020	2021	2022	2023	2024	2025	2026	2027	2028	2029	2030
Code	G	Н		J	K	L	М	Ν	0	Р	R	S
Month	Jan	Feb	Mar	Apr	Мау	Jun	Jul	Aug	Sep	Oct	Nov	Dec



# Maximum Ratings (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit		
Drain-Source Voltage	Vdss	-20	V		
Gate-Source Voltage	Vgss	±6	V		
Continuous Drain Current (Note 6) $V_{GS}$ = -4.5V	Steady State	TA = +25°C T <sub>A</sub> = +75°C	ID	-0.5 -0.4	А
Maximum Continuous Body Diode Forward Currer	nt (Note 6)		ls	-0.39	А
Pulsed Drain Current (10µs Pulse, Duty Cycle = 1	%)		IDM	-2.5	А

## Thermal Characteristics (@TA = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit	
Total Power Dissipation (Note 5)	Steady State	PD	0.25	W
Thermal Resistance, Junction to Ambient (Note 5)	Steady State	Reja	496	°C/W
Total Power Dissipation (Note 6)	Steady State	PD	0.32	W
Thermal Resistance, Junction to Ambient (Note 6)	Steady State	RθJA	395	°C/W
Operating and Storage Temperature Range		TJ, TSTG	-55 to +150	°C

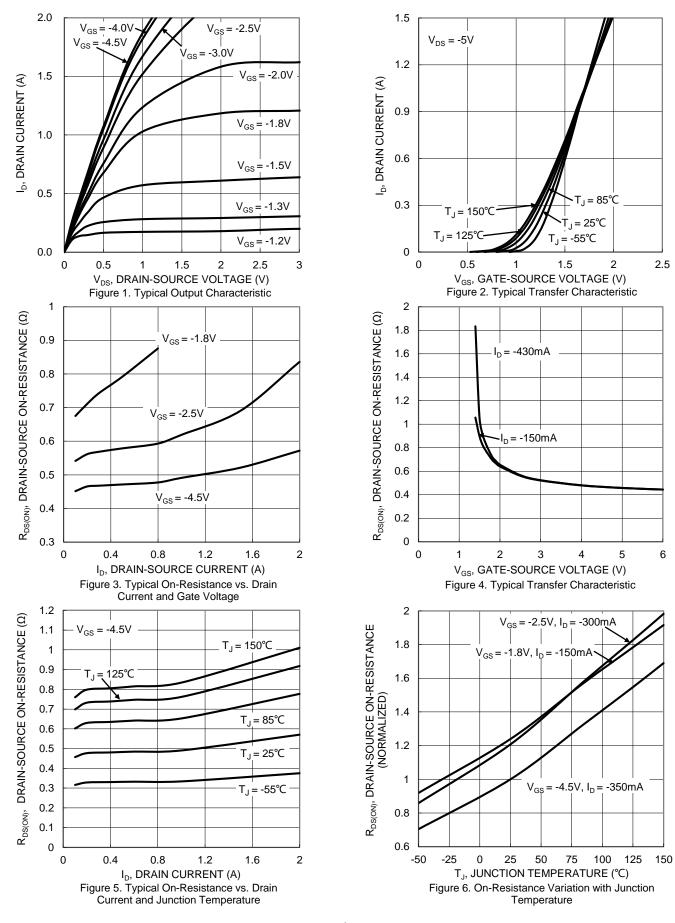
## Electrical Characteristics (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition	
OFF CHARACTERISTICS (Note 7)							
Drain-Source Breakdown Voltage	BVDSS	-20	—	—	V	$V_{GS} = 0V, I_{D} = -250 \mu A$	
Zero Gate Voltage Drain Current $T_J = +25^{\circ}C$	IDSS		—	-100	nA	$V_{DS} = -20V, V_{GS} = 0V$	
Gate-Source Leakage	lgss	_	—	±2.0	μA	$V_{GS} = \pm 4.5 V$ , $V_{DS} = 0 V$	
ON CHARACTERISTICS (Note 7)							
Gate Threshold Voltage	Vgs(th)	-0.5	—	-1.0	V	$V_{DS} = V_{GS}$ , $I_D = -250 \mu A$	
			0.4	0.7		V <sub>GS</sub> = -4.5V, I <sub>D</sub> = -430mA	
Static Drain-Source On-Resistance	R <sub>DS(ON)</sub>		0.5	0.9	Ω	$V_{GS} = -2.5V, I_D = -300mA$	
			0.7	1.3		VGS = -1.8V, ID = -150mA	
Diode Forward Voltage (Note 7)	Vsd	_	-0.7	-1.2	V	Vgs = 0V, Is = -150mA	
DYNAMIC CHARACTERISTICS (Note 8)							
Input Capacitance	Ciss		49	-	pF		
Output Capacitance	Coss	_	12	—	pF	VDS = -16V, VGS = 0V, f = 1.0MHz	
Reverse Transfer Capacitance	Crss	_	3.4	—	pF		
Total Gate Charge	Qg	_	0.7	—	nC		
Gate-Source Charge	Qgs	_	0.1	—	nC	V <sub>GS</sub> = -4.5V, V <sub>DS</sub> = -10V, ID = -250mA	
Gate-Drain Charge	Q <sub>gd</sub>	_	0.1	—	nC	ID = -250 IIIA	
Turn-On Delay Time	tD(ON)	_	5.3	—	ns		
Turn-On Rise Time	tR	_	2.8	—	ns	$V_{DD} = -10V, V_{GS} = -4.5V,$	
Turn-Off Delay Time	t <sub>D(OFF)</sub>		1247	—	ns	$R_{L} = 47\Omega, R_{G} = 10\Omega,$ D = -200 mA	
Turn-Off Fall Time	tF	_	445	—	ns		
Reverse Recovery Time	trr		10.5	—	ns	1 - 10.0	
Reverse Recovery Charge	Q <sub>RR</sub>	_	1.8	—	nC	l <sub>F</sub> = -1A, di/dt = 100A/μs	

 Device mounted on FR-4 substrate PC board, 2oz copper, with minimum recommended pad layout.
 Device mounted on FR-4 substrate PC board, 2oz copper, with 1inch square copper plate.
 Short duration pulse test used to minimize self-heating effect. Notes:

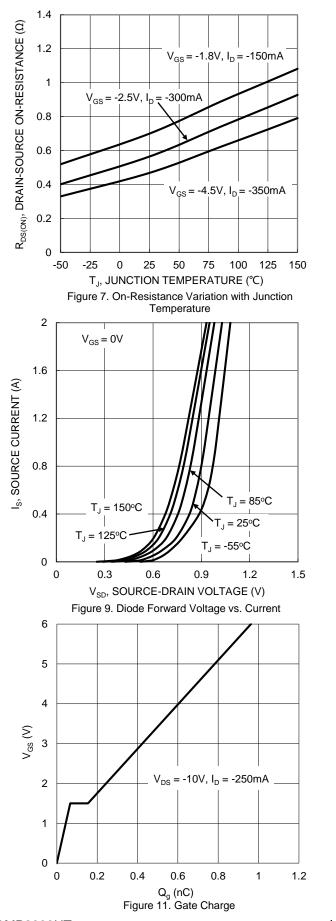
8. Guaranteed by design. Not subject to production testing.

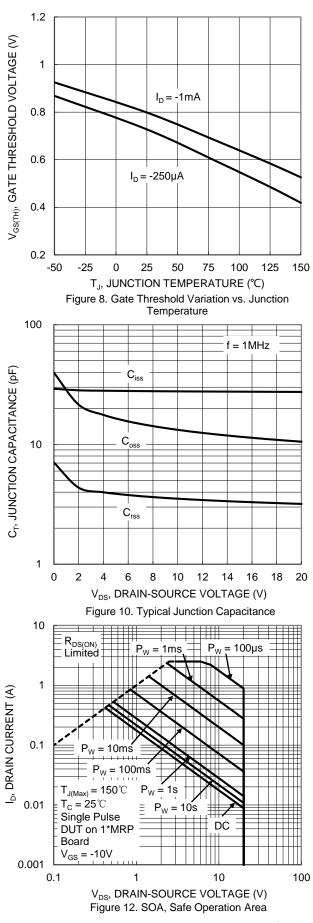






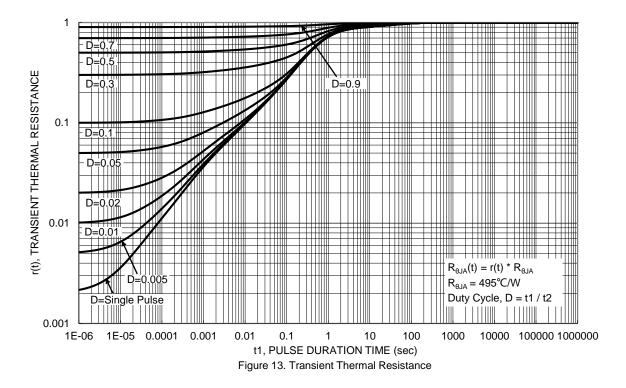






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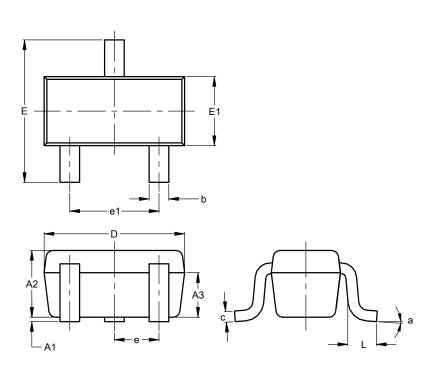






## **Package Outline Dimensions**

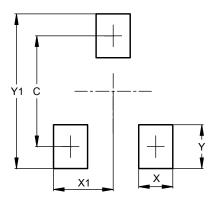
Please see http://www.diodes.com/package-outlines.html for the latest version.



	SOT523								
Dim	Min	Max	Тур						
A1	0.00	0.10	0.05						
A2	0.60	0.80	0.75						
A3	0.45	0.65	0.50						
b	0.15	0.30	0.22						
С	0.10	0.20	0.12						
D	1.50	1.70	1.60						
Е	1.45	1.75	1.60						
E1	0.75	0.85	0.80						
е		0.50 BS	С						
e1	0.90	1.10	1.00						
L	0.20	0.40	0.33						
а	0°		8°						
A	All Dimensions in mm								

## **Suggested Pad Layout**

Please see http://www.diodes.com/package-outlines.html for the latest version.



SOT523

Dimensions	Value (in mm)
С	1.29
Х	0.40
X1	0.70
Y	0.51
Y1	1.80

SOT523



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